

## Power Schottky rectifier

## Main product characteristics

I <sub>F(AV)</sub>	3 A
V <sub>RRM</sub>	150 V
T <sub>j</sub> (max)	175° C
V <sub>F</sub> (max)	0.67 V

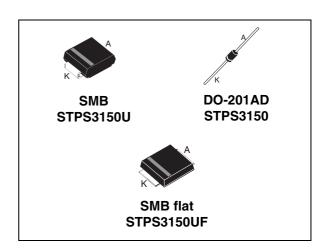
### Features and benefits

- Negligible switching losses
- Low forward voltage drop for higher efficiency and extented battery life
- Low thermal resistance

## **Description**

150 V Power Schottky rectifier are suited for switch mode power supplies on up to 24 V rails and high frequency converters.

Packaged in Axial, SMB, and low-profile SMB, this device is intended for use in consumer and computer applications like TV, STB, PC and DVD where low drop forward voltage is required to reduce power dissipation.



### **Order Codes**

Part Number	Marking
STPS3150U	G315
STPS3150	STPS3150
STPS3150RL	STPS3150
STPS3150UF	FG315

Table 1. Absolute Ratings (limiting values)

Symbol	Parameter			Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	Repetitive peak reverse voltage			V
		SMB	$T_L = 130^{\circ} \text{ C}  \delta = 0.5$	3	А
I <sub>F(AV)</sub>	I <sub>F(AV)</sub> Average forward current	DO-201AD	$T_L = 140^{\circ} \text{ C}  \delta = 0.5$		
		SMB flat	$T_L = 150^{\circ} \text{ C}  \delta = 0.5$		
		SMB		100	
$I_{FSM}$	Surge non repetitive forward current	DO-201AD	t <sub>p</sub> = 10 ms sinusoidal	150	Α
		SMB flat		100	
T <sub>stg</sub>	Storage temperature range	•	•	-65 to + 175	° C
Tj	Operating junction temperature <sup>(1)</sup>			175	° C

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Characteristics STPS3150

## 1 Characteristics

Table 2. Thermal resistance

Symbol	Parameter			Value	Unit
			SMB flat	10	
R <sub>th(j-l)</sub>	Junction to lead		SMB	20	° C/W
		Lead length = 10 mm	DO-201AD	15	

Table 3. Static electrical characteristics

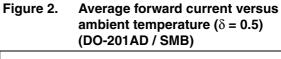
Symbol	Parameter	Tests conditions		Min.	Тур	Max.	Unit
I <sub>R</sub> <sup>(1)</sup> Reverse leakage c	Reverse leakage current	T <sub>j</sub> = 25° C	$V_R = V_{RRM}$		0.4	2.0	μΑ
'R`	IR . / neverse leakage current	T <sub>j</sub> = 125° C			0.6	2.0	mA
	V (2) Familiard valle and during	T <sub>j</sub> = 25° C	I <sub>F</sub> = 3 A		0.78	0.82	
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 125° C			0.63	0.67	V
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25° C	I 6 A		0.85	0.89		
		T <sub>j</sub> = 125° C	I <sub>F</sub> = 6 A		0.70	0.75	

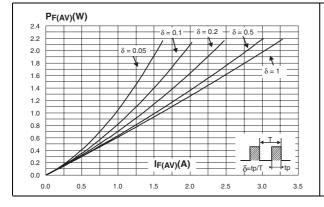
<sup>1.</sup>  $t_p = 5 \text{ ms}, \ \delta < 2\%$ 

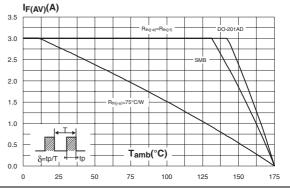
To evaluate the conduction losses use the following equation:

$$P = 0.59 \times I_{F(AV)} + 0.023 I_{F^{2}(RMS)}$$

Figure 1. Average forward power dissipation versus average forward current







<sup>2.</sup>  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

STPS3150 Characteristics

Figure 3. Average forward current versus ambient temperature ( $\delta$  = 0.5) (SMB flat)

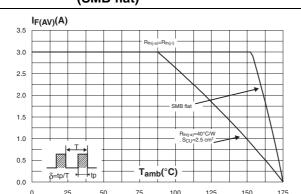


Figure 4. Non repetitive surge peak forward current versus overload duration (maximum values) (SMB)

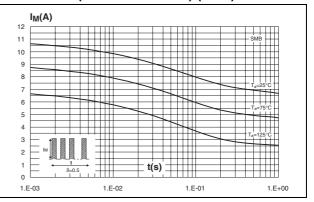


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values) (DO-201AD)

Imaximum values)

Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values)

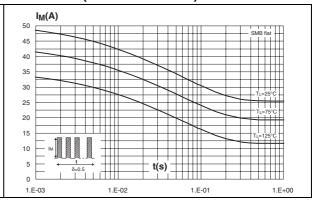
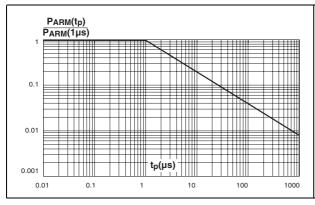
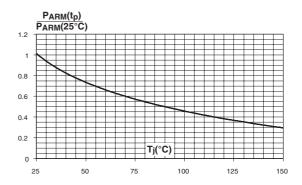


Figure 7. Normalized avalanche power derating versus pulse duration

Figure 8. Normalized avalanche power derating versus junction temperature





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Figure 9. Relative variation of thermal impedance junction to ambient versus pulse duration (SMB)

Zth(j-a)/Rth(j-a)

1.0

9.8

0.7

0.6

0.5

0.4

0.3

0.2

Single pulse

0.1

tp(s)

\$\delta = \text{tp} T \text{tp} \text{tp}

Figure 10. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-2001AD)

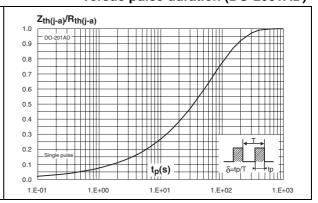


Figure 11. Relative variation of thermal impedance junction to lead versus pulse duration - SMB flat

Versus pulse duration - SMB flat

Zth(j-l)/Rth(j-l)

1.0

9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

Single pulse

0.1

1.E-04

1.E-03

1.E-02

1.E-01

1.E+00

1.E+01

Figure 12. Reverse leakage current versus reverse voltage applied (typical values)

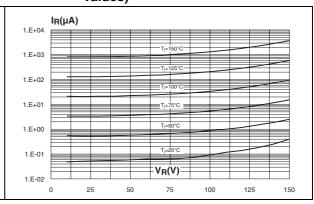
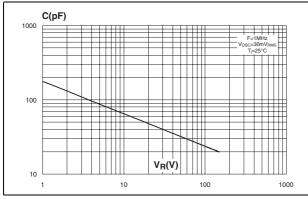
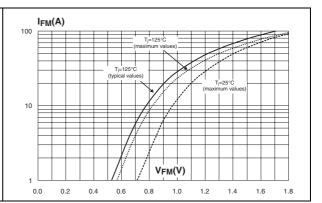


Figure 13. Junction capacitance versus reverse voltage applied (typical values)

Figure 14. Forward voltage drop versus forward current

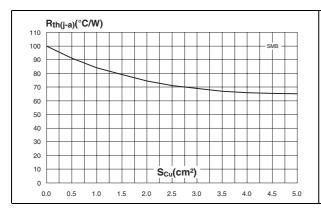




STPS3150 Characteristics

Figure 15. Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4,  $e_{CU}$  = 35  $\mu$ m) (SMB)

Figure 16. Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4,  $e_{CU}$  = 35  $\mu$ m) (DO-201AD)



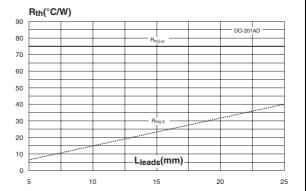
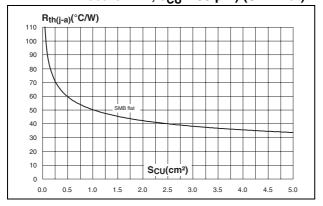


Figure 17. Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4,  $e_{CU}$  = 35  $\mu$ m) (SMB flat)



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Package information STPS3150

### **Package information** 2

Epoxy meets UL94, V0.

Table 4. **SMB** dimensions

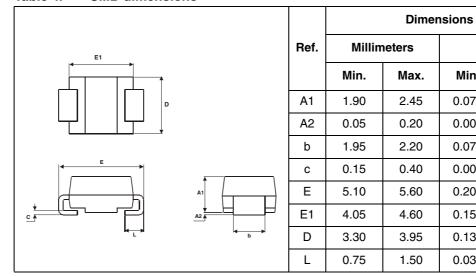
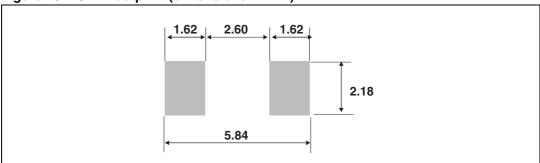


Figure 18. SMB footprint (dimensions in mm)



Inches

Max.

0.096

0.008

0.087

0.016

0.220

0.181

0.156

0.059

Min.

0.075

0.002

0.077

0.006

0.201

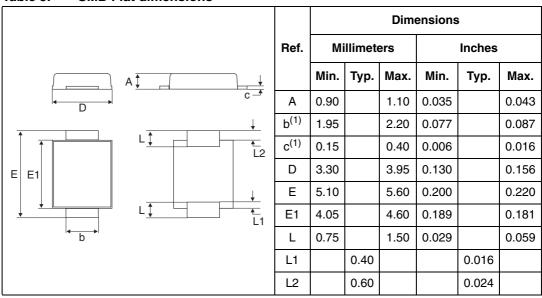
0.159

0.130

0.030

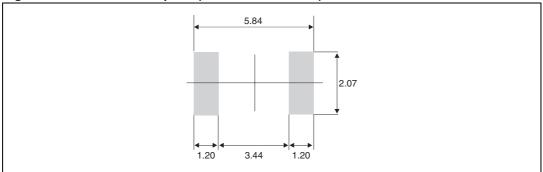
STPS3150 Package information

Table 5. SMB Flat dimensions



<sup>1.</sup> Applies to plated leads

Figure 19. SMB Flat footprint (dimensions in mm)



Package information STPS3150

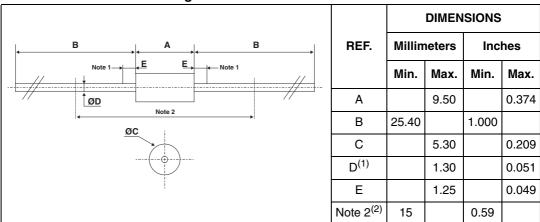


Table 6. DO-201AD Package dimensions

- 1. The lead diameter D is not controlled over zone E
- 2. The minimum length, which must stay straight between the right angles after bending, is 15 mm (0.59")

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# 3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS3150U	G315	SMB	0.107 g	2500	Tape and reel
STPS3150UF	FG315	SMB flat	0.50 g	5000	Tape and reel
STPS3150	STPS3150	DO-201AD	1.12 g	600	Ammopack
STPS3150RL	STPS3150	DO-201AD	1.12 g	1900	Tape and reel

## 4 Revision history

Date	Revision	Description of Changes
May-2003	2A	Last update.
31-May-2006	3	Reformatted to current standard. Added ECOPACK statement. Updated SMB footprint in Figure 12. Changed nF to pF in Figure 8.
08-Feb-2007	4	Added SMB flat package.

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